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	THE DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO
09/911,444	67/25/2001	Tomasz Klosowiak	212020US99	4668
OBLON, SPIVAK, MCCLELLAND, MAIER & NEUSTADT, 1940 DUKE STREET			C. EXAMINER FORDE, REMMON R	
ALEXANDRI	A, VA 22314		ART UNIT	PAPER NUMBER
			2826 DATE MAILED: 05/22/200	3 /C

Please find below and/or attached an Office communication concerning this application or proceeding.

		Application No.	Applicant(s)	\mathcal{U}
,	j	09/911,444	KLOSOWIAK ET A	\L.
			Art Unit	
Office Ac	ction Summary	Examiner Rommon R. Fordé	2826	
	G DATE of this communication app	Remmon R. Fordé	vith the correspondence ad	dress
The MAILING	3 DATE of this communication ap	poars on the cover sheet (
Period for Reply	TATUTORY PERIOD FOR REPL'	Y IS SET TO EXPIRE 3	MONTH(S) FROM	
THE MAILING DAT Extensions of time may be after SIX (6) MONTHS from the period for reply specified by the period for reply is second for reply in the period for reply within the period for reply within the period patent term adjusted by the period for reply market by the period patent term adjusted by the period for th	be available under the provisions of 37 CFR 1.1 from the mailing date of this communication. lecified above is less than thirty (30) days, a rep specified above, the maximum statutory period se set or extended period for reply will, by statuthe Office later than three months after the mailing ustment. See 37 CFR 1.704(b).	ply within the statutory minimum of the statutory and will expire SIX (6) Minimum to become the statutory of the statut	thirty (30) days will be considered timel	aly. communication.
Status	e to communication(s) filed on 14	1 <u>March 2003</u>		
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closed in a	application is in condition for allow accordance with the practice undense	wance except for formal r er Ex parte Quayle, 1935	(C.D. 11, 453 O.G. 213.	
	47 inforce pending in the applicall	non.		١
4a) Of the a	above claim(s) <u>14-17</u> is/are withdi	rawn trom consideration.		į
. 5) Claim(s)	is/are allowed.			
6)⊠ Claim(s) <u>1</u> -	<u>-13</u> is/are rejected.			
	in/ore objected to.		t	
	are subject to restriction an	nd/or election requiremen	и.	
Application Papers	8			
		niner.	by the Examiner.	
10) The drawin	ng(s) filed on is/are: a)∐ a	accepted of b) be hold in	abevance. See 37 CFR 1 85	i(a).
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· ·	a correction tiled oil	13. 4/11		
	and corrected drawings are required	11 1 3		
12) The oath o	or declaration is objected to by th	ne Examiner.		
Driority under 35 !	U.S.C. §§ 119 and 120		S.C. 8 119(a)-(d) or (f)	
40\ Asland	U.S.C. §§ 119 and 120 ledgment is made of a claim for fo	oreign priority under 35 ປ	1.0.0. 8 1 10(a)-(u) of (1).	
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		ıments have been receive	ed.	
1. C	ertified copies of the priority docu certified copies of the priority docu	iments have been receive	ed in Application No	– lional Stage
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14)∐ Acknowle	edgment is made of a claim for do e translation of the foreign langua	age provisional applicatio	n has been received.	· /
a) ☐ The 15)☐ Acknowl	e translation of the foreign langua ledgment is made of a claim for d	domestic priority under 35	5 U.S.C. §§ 120 and/or 121	1.
Attachment(s)		_	Interview Summary (170-413)	aper No(s) atioh(PTQ-152)
1) Notice of Refe	erences Cited (PTO-892) ftsperson's Patent Drawing Review (PTO-	o-948) 5) 🔲	Notice of Informal Pate Notice Other CUDE DVISOBY Pa	ATOT EXAMINEH
3) 🔀 Information Di	bisclosure Statement(3) (* * * * * * * * * * * * * * * * * * *	Office Action Summary	TECHNO! CGY Part of Par	

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DETAILED ACTION

Response To Restriction

Examiner hereby acknowledges Applicant's election of claims 1-13 drawn to the embodiment of Figures 1-8 and 38 in the correspondence dated 2/19/03 and also agrees that with the adding of Figure 38 to the elected group of Figures that all claims 1-13 should be examined. However, the Examiner hereby disagrees with the Applicant's initial election of Group I, claims 1-13, with traverse in Paper No. 4 on the grounds that Group I, claims 1-13, and Group II, claims 14-17 can be searched together without and undue burden on the Examiner. This is not found persuasive because there still is an undue burden on the examiner as pointed out in Paper No. 2.

The requirement is still deemed proper and is therefore made FINAL.

Claim Rejections - 35 USC § 103

The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:

(a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.

Claims 1-13 are rejected under 35 U.S.C. 103(a) as being unpatentable over Hata et al. in view of Wersing et al..

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Regarding claims 1-13, referencing Figure 1, Hata et al. discloses a semiconductor structure provided with a monocrystalline silicon substrate (1); an amorphous oxide material (silicon dioxide) (2) overlying the monocrystalline silicon substrate; a monocrystalline perovskite oxide material (MgO) (3) overlying the amorphous oxide material; a monocrystalline compound semiconductor material (Column 7, lines 2-9.) Lastly, Hata et al. further that it is possible to form a three dimensional semiconductor device, a composite semiconductor device, a high performance semiconductor memory device or the like on his final crystalline semiconductor substrate to obtain a semiconductor device which is new and highly integrated at an inexpensive cost. (Column 3, line 31 – Column 7, line 14.)

Referencing Figure 1, Hata et al. doesn't disclose providing an optical processing layer to overly the monocrystalline compound semiconductor layer.

However, referencing Figures 1-5, Wersing et al. discloses that it is desirable and very well known in the art to grow various optical devices (i.e. a pyrodetector) on top of monocrystalline substrates especially those with improved crystalline structures to fabricate more reliable and inexpensive semiconductor devices. (Column 5, line 9 – Column 6, line 63.)

Therefore, it would have been obvious to one of ordinary skill in the art at the time the invention was made for Hata et al. to place an optical processing layer/optical device on his improved monocrystalline compound layer/monocrystalline substrate as disclosed by Wersing et al. because Wersing et al. discloses that it is desirable and very well known in the art to grow various optical devices on top of monocrystalline

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substrates especially those with improved crystalline structures to fabricate more reliable and inexpensive semiconductor devices. Furthermore, since Hata does disclose that various devices can be fabricated on his new, highly integrated, and inexpensive substrate it can logically be expected that providing an optical device on his substrate would have been a mere obvious design choice.

Relevant Prior Art

The prior art made of record and not relied upon is considered pertinent to applicant's disclosure.

Guenzer, Hung et al., Hasegawa et al. and Neville Connell et al. disclose monocrystalline substrate devices.

Contact Information

Any inquiry concerning this communication or earlier communications from the examiner should be directed to Remmon R. Fordé whose telephone number is (703) 305-4533. The examiner can normally be reached on Monday-Friday (8:00-4:30).

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Nathan J. Flynn can be reached on (703) 308-6601. The fax phone numbers for the organization where this application or proceeding is assigned are (703)

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308-5841 for regular communications and (703) 308-5841 for After Final communications.

Any inquiry of a general nature or relating to the status of this application or proceeding should be directed to the receptionist whose telephone number is (703) 308-0956.

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Remmon R. Fordé May 18, 2003